

STA3350D

PNP Silicon Transistor

Applications

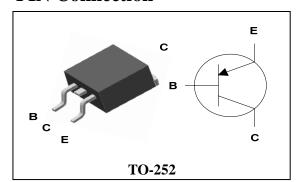
- Power amplifier application
- High current switching application

Features

- Low saturation voltage: $V_{CE(sat)}$ =-0.15V Typ. @ I_{C} =-1A, I_{B} =-50mA
- Large collector current capacity: I_C=-3A
- "Green" device and RoHS compliant device
- Available in full lead (Pb)-free device

RoHS 🕅

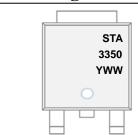
PIN Connection



Ordering Information

Type NO.	Marking	Package Code
STA3350D	STA3350	TO-252

Marking Information



Column 1, 2 : Device Code

Column 3: Year & Week Code

Absolute Maximum Ratings

[Ta=25°C]

Characteristic	Symbol	Rating	Unit	
Collector-base voltage	V_{CBO}	-50	V	
Collector-emitter voltage	V_{CEO}	-50	V	
Emitter-base voltage	V_{EBO}	-6	V	
Collector current	I_{C}	-3	A(DC)	
Collector current	I _{CP} *	-50 -50 -6	A(Pulse)	
Collector Dower dissipation	P _C (Ta= 25°C)	1.2	W	
Collector Power dissipation	$P_C(T_C = 25^{\circ}C)$	-50 -50 -6 -3 -6 1.2 15 150	W	
Junction temperature	T ₁	150	°C	
Storage temperature range	T _{stg}	-55~150	°C	

*: Single pulse, tp= 300 μ s

Characteristic		Symbol	Тур.	Max	Unit
Thermal resistance	Junction-ambient	$R_{th(J\text{-}A)}$	-	104.1	°C/W
	Junction-case	$R_{th(J\text{-}C)}$	-	8.3	°C/W

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Electrical Characteristics

[Ta=25℃]

Charac	eteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-emitter b	oreakdown voltage	BV _{CEO}	I _C =-1mA, I _B =0 -50 -		-	ı	٧
Collector cut-off cu	urrent	I_{CBO}	V _{CB} =-50V, I _E =0	1		μΑ	
Emitter cut-off cur	rent	I_{EBO}	V _{EB} =-6V, I _C =0	1		-1	μΑ
DC current gain		h _{FE}	V _{CE} =-2V, I _C =-0.5A*	5A* 120 - 240		240	
DC current gain	ent gain —		V _{CE} =-2V, I _C =-2A*	40	-	1	
Collector-emitter s	saturation voltage	$V_{\text{CE(sat)}}$	I _C =-1A, I _B =-0.05A*	0.35		V	
Base-emitter satu	ration voltage	$V_{BE(sat)}$	I _C =-2A, I _B =-0.1A*	-	-0.97	-1.2	V
Transition frequen	су	f_{T}	V _{CE} =-10V, I _C =-0.05A	-	250	-	MHz
Collector output ca	Collector output capacitance		V _{CB} =-10V, I _E =0, f=1MHz	-	28	-	pF
Switching Time	Turn-on Time	t _{on}	Ise indict is OUTPUT	-	100	-	
	Storage Time	t _{stg}	IBE INPUT IBE OUTPUT Sous INPUT IBE SOUS IBE SO	-	300	-	ns
	Fall Time	t _f	-IB=IB≃IUUMA -30V DUTY CYCLE ≤1%	-	50	-	

^{*:} Pulse test : $t_P \le 300 \mu s$, Duty cycle $\le 2\%$

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Fig. 1 P_C - T_a

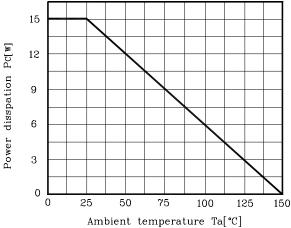


Fig. 3 $I_{\rm C}$ - $V_{\rm CE}$

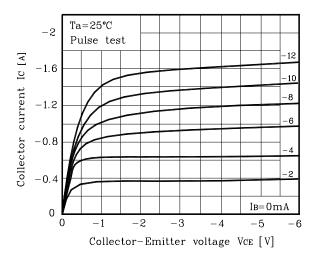


Fig. 5 $V_{\text{CE(sat)}}$ - I_{C}

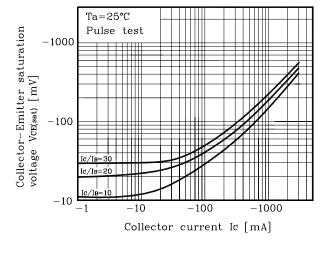


Fig. 2 $I_{C}\;$ - V_{BE}

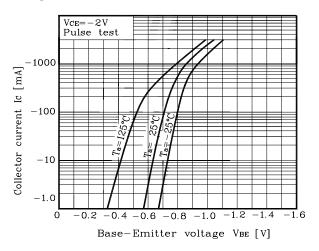


Fig. 4 h_{FE} - I_C

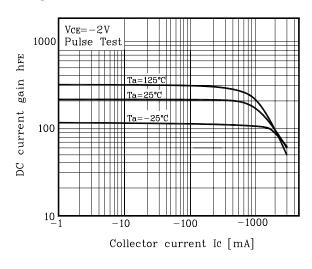
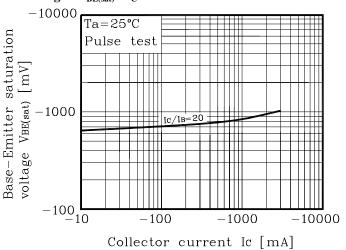


Fig. 6 $V_{BE(sat)}$ - I_{C}



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Electrical Characteristic Curves

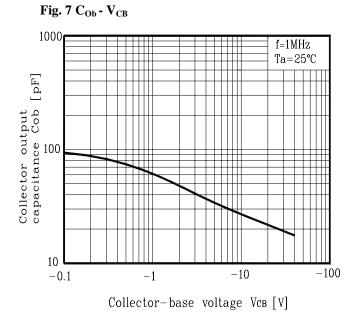
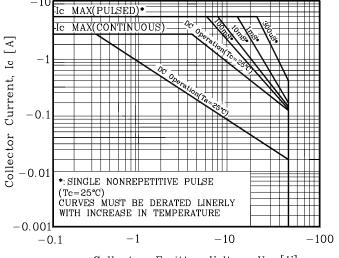
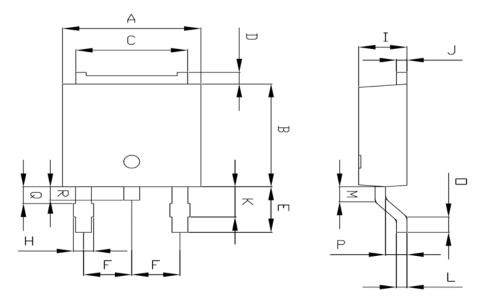


Fig. 8 Safe Operating Area



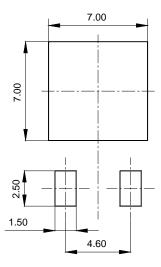
 ${\tt Collector-Emitter\ Voltage\ Vde\ [V]}$

Outline Dimension



	MILLIMETERS			NOTE
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	NOTE
Α	6.40	6.60	6.80	
В	5.90	6.10	6.30	
C	5.04	5.34	5.64	
D	0.50	0.70	0.90	
E	2.50	2.70	2.90	
F	2.10	2.30	2.50	
Н				
- 1	2.20	2.30	2.40	
J	0.40	0.50	0.60	
K	1.60	1.80	2.00	
L	0.40	0.50	0.60	
М	0.81	0.91	1.01	
0	0.80	0.90	1.00	
Р	0.90	1.00	1.10	
Q		0.95 MAX		
R	0.60	0.80	1.00	

*Recommend PCB solder land [Unit: mm]



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